# Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low  $V_F = 0.455 \text{ V}$  at  $I_F = 5 \text{ A}$ 

## **Features**

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- This is a Pb-Free Package

## **Typical Applications**

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

## **Mechanical Characteristics**

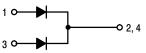
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



## ON Semiconductor®

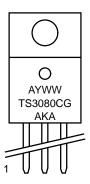
www.onsemi.com

## PIN CONNECTIONS





#### **MARKING DIAGRAMS**



A = Assembly Location

Y = Year

WW = Work Week

AKA = Polarity Designator G = Pb-Free Package

## **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### **MAXIMUM RATINGS**

Rating		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	80	V
Average Rectified Forward Current (Rated V <sub>R</sub> , T <sub>C</sub> = 115°C)	Per device Per diode	I <sub>F(AV)</sub>	30 15	A
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz, T <sub>C</sub> = 110°C)	Per device Per diode	I <sub>FRM</sub>	60 30	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I <sub>FSM</sub>	160	А
Operating Junction Temperature		TJ	-40 to +150	°C
Storage Temperature		T <sub>stg</sub>	-40 to +150	°C
Voltage Rate of Change (Rated V <sub>R</sub> )		dv/dt	10,000	V/µs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS

Rating		Symbol	Value	Unit
Maximum Thermal Resistance (insertion mounted to 1 oz FR4 Board)	Junction-to-Case	$R_{\theta JC}$	4.0	°C/W
(insertion mounted to 1 oz FR4 Board)	Junction-to-Ambient	$R_{\theta JA}$	105	°C/W

<sup>1.</sup> Junction-to-Case, using large Heatsink attached to device.

### **ELECTRICAL CHARACTERISTICS** (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Max	Unit
Maximum Instantaneous Forward Voltage (Note 3)	V <sub>F</sub>			V
$(I_F = 5 \text{ A}, T_J = 25^{\circ}\text{C})$		0.516	_	
$(I_F = 7.5 \text{ A}, T_J = 25^{\circ}\text{C})$ $(I_F = 15 \text{ A}, T_J = 25^{\circ}\text{C})$		0.576 0.734	0.85	
(I <sub>F</sub> = 5 A, T <sub>J</sub> = 125°C)		0.455	_	
$(I_F = 7.5 \text{ A}, T_J = 125^{\circ}\text{C})$		0.522	_	
(I <sub>F</sub> = 15 A, T <sub>J</sub> = 125°C)		0.627	0.68	
Maximum Instantaneous Reverse Current (Note 3) (Rated dc Voltage, T <sub>J</sub> = 25°C)	I <sub>R</sub>	20	700	μΑ
(Rated dc Voltage, T <sub>J</sub> = 125°C)		8	30	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **ORDERING INFORMATION**

Device	Package	Shipping
NTSJ3080CTG	TO-220FB (Pb-Free)	50 Units / Rail

<sup>2.</sup> Junction-to-Ambient, using with no Heatsink.

<sup>3.</sup> Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq 2.0\%$ 

### **TYPICAL CHARACTERISITICS**

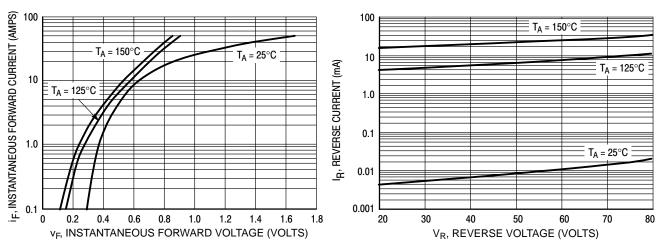


Figure 1. Typical Forward Voltage

**Figure 2. Typical Reverse Current** 

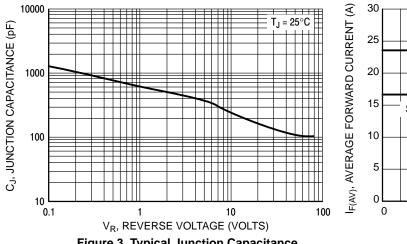


Figure 3. Typical Junction Capacitance

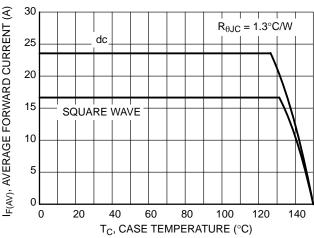
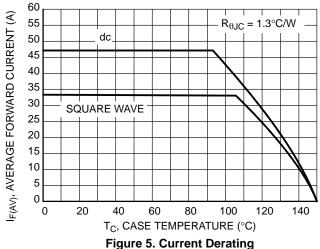


Figure 4. Current Derating per Leg



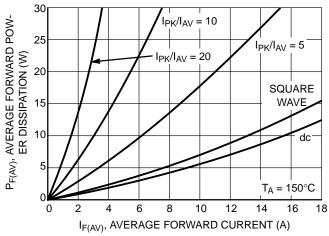


Figure 6. Forward Power Dissipation

## **TYPICAL CHARACTERISITICS**

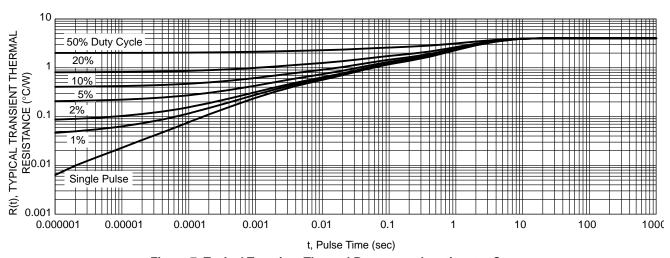
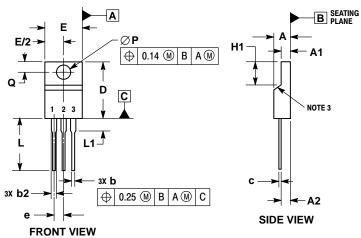


Figure 7. Typical Transient Thermal Response, Junction-to-Case

#### PACKAGE DIMENSIONS

### TO-220 FULLPACK, 3-LEAD

CASE 221AH ISSUE F

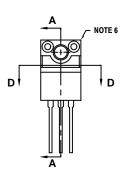


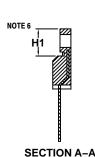
### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
- CONTOUR UNCONTROLLED IN THIS AREA.
   DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE. PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.
- DIMENSION 62 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.
- CONTOURS AND FEATURES OF THE MOLDED PACKAGE BODY MAY VARY WITHIN THE ENVELOP DEFINED BY DIMENSIONS A1 AND H1 FOR MANUFACTURING PURPOSES.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.30	4.70	
A1	2.50	2.90	
A2	2.50	2.90	
b	0.54	0.84	
b2	1.10	1.40	
С	0.49	0.79	
D	14.70	15.30	
E	9.70	10.30	
е	2.54 BSC		
H1	6.60	7.10	
L	12.50	14.73	
L1		2.80	
P	3.00	3.40	
Q	2.80	3.20	







**ALTERNATE CONSTRUCTION** 

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="https://www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center

Phone: 81–3–5817–1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative